

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	187.8000 m	187.3074 m	N/A
RT2	4.2652	278.7399 m	N/A
RT3	12.0824	515.2316 m	N/A
RT4	48.4646	518.7211 m	N/A
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	550.3966 u	29.6519 m	N/A
CT2	28.5670 m	1.8315 m	N/A
CT3	169.0130 m	36.8007 m	N/A
CT4	1.3525	36.1818 m	N/A

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )			
Junction to	Ambient	Case	Foot
RF1	219.0000 m	366.7631 m	N/A
RF2	9.3477	424.4648 m	N/A
RF3	13.0204	151.2332 m	N/A
RF4	42.4129	557.5389 m	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )			
Junction to	Ambient	Case	Foot
CF1	364.0140 u	1.6457 m	N/A
CF2	34.4002 m	9.2684 m	N/A
CF3	269.8512 m	1.9848 m	N/A
CF4	1.2734	13.4666 m	N/A

**Note**

NA indicates not applicable

